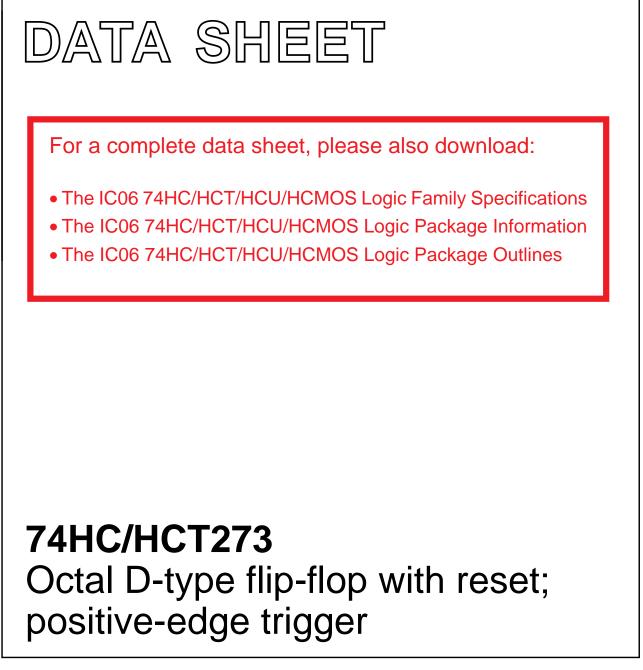
INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC06 September 1993



74HC/HCT273

FEATURES

- Ideal buffer for MOS microprocessor or memory
- Common clock and master reset
- Eight positive edge-triggered D-type flip-flops
- See "377" for clock enable version
- See "373" for transparent latch version
- See "374" for 3-state version
- Output capability; standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT273 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT273 have eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common clock (CP) and master reset (\overline{MR}) inputs load and reset (clear) all flip-flops simultaneously.

The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding output (Q_n) of the flip-flop.

All outputs will be forced LOW independently of clock or data inputs by a LOW voltage level on the $\overline{\text{MR}}$ input.

The device is useful for applications where the true output only is required and the clock and master reset are common to all storage elements.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

SYMBOL	PARAMETER	CONDITIONS	TYF	PICAL	UNIT
	FARAMETER	CONDITIONS	НС	нст	
t _{PHL/} t _{PLH}	propagation delay	C _L = 15 pF; V _{CC} = 5 V			
	CP to Q _n		15	15	ns
	MR to Q _n		15	20	ns
f _{max}	maximum clock frequency		66	36	MHz
CI	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per flip-flop	notes 1 and 2	20	23	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 P_{D} = $C_{PD} \times V_{CC}{}^{2} \times f_{i} + \Sigma \; (C_{L} \times V_{CC}{}^{2} \times f_{o})$ where:

 f_i = input frequency in MHz

 $f_o = output frequency in MHz$

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs}$

 C_L = output load capacitance in pF

 V_{CC} = supply voltage in V

2. For HC the condition is V_1 = GND to V_{CC} For HCT the condition is V_1 = GND to V_{CC} – 1.5 V

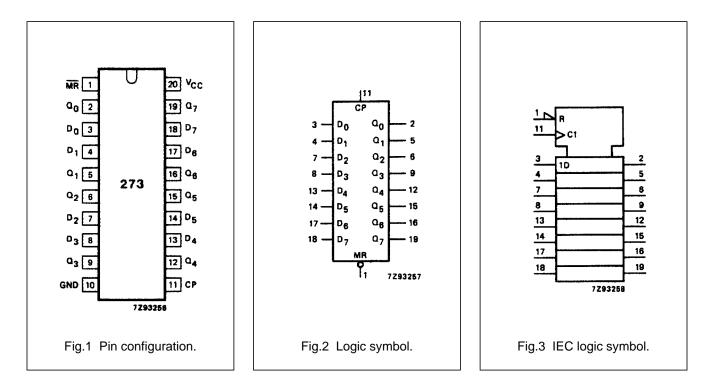
ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

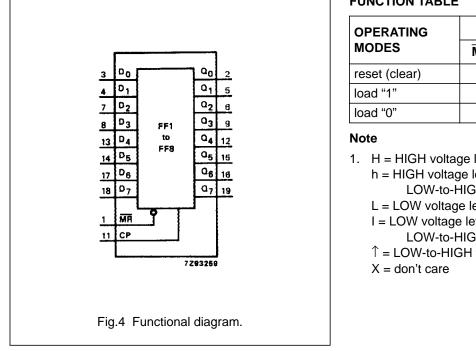
74HC/HCT273

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	MR	master reset input (active LOW)
2, 5, 6, 9, 12, 15, 16, 19	Q ₀ to Q ₇	flip-flop outputs
3, 4, 7, 8, 13, 14, 17, 18	D ₀ to D ₇	data inputs
10	GND	ground (0 V)
11	СР	clock input (LOW-to-HIGH, edge-triggered)
20	V _{CC}	positive supply voltage



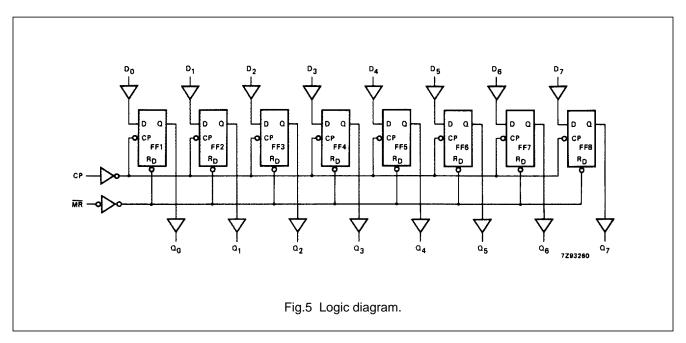
74HC/HCT273



FUNCTION TABLE

OPERATING		INPUTS	OUTPUTS		
MODES	MR	СР	D _n	Q _n	
reset (clear)	L	X	Х	L	
load "1"	Н	\uparrow	h	Н	
load "0"	Н	1	I	L	

- 1. H = HIGH voltage level
 - h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition
 - L = LOW voltage level
 - I = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition
 - \uparrow = LOW-to-HIGH transition



74HC/HCT273

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications".

Output capability: standard I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS	
		74HC									
		+25			-40 to +85		-40 to +125			V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.	1	(*)	
t _{PHL} / t _{PLH}	propagation delay CP to Q _n		41 15 13	150 30 26		185 37 31		225 45 38	ns	2.0 4.5 6.0	Fig.6
t _{PHL}	propagation delay MR to Q _n		44 16 14	150 30 26		185 37 31		225 45 38	ns	2.0 4.5 6.0	Fig.7
t _{THL} / t _{TLH}	output transition time		19 7 6	75 15 13		95 19 15		110 22 19	ns	2.0 4.5 6.0	Fig.6
t _W	clock pulse width HIGH or LOW	80 16 14	14 5 4		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig.6
t _W	master reset pulse width LOW	60 12 10	17 6 5		75 15 13		90 18 15		ns	2.0 4.5 6.0	Fig.7
t _{rem}	removal time MR to CP	50 10 9	6 2 2		65 13 11		75 15 13		ns	2.0 4.5 6.0	Fig.7
t _{su}	set-up time D _n to CP	60 12 10	11 4 3		75 15 13		90 18 15		ns	2.0 4.5 6.0	Fig.8
t _h	hold time D _n to CP	3 3 3	6 2 2		3 3 3		3 3 3		ns	2.0 4.5 6.0	Fig.8
f _{max}	maximum clock pulse frequency	6.0 30 35	20.6 103 122		4.8 24 28		4.0 20 24		MHz	2.0 4.5 6.0	Fig.6

74HC/HCT273

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications".

Output capability: standard I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT						
MR	1.00						
CP	1.75						
D _n	0.15						

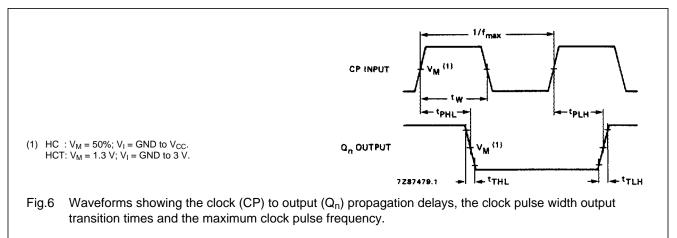
AC CHARACTERISTICS FOR 74HCT

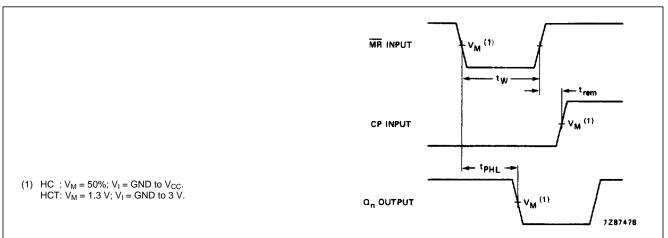
GND = 0 V; $t_r = t_f = 6 ns$; $C_L = 50 pF$

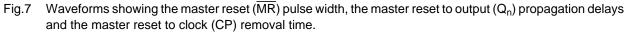
SYMBOL	PARAMETER	T _{amb} (°C) 74HCT								TEST CONDITIONS	
		+25			-40 to +85		-40 to +125		UNIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.			
t _{PHL} / t _{PLH}	propagation delay CP to Q _n		16	30		38		45	ns	4.5	Fig.6
t _{PHL}	propagation delay MR to Q _n		23	34		43		51	ns	4.5	Fig.7
t _{THL} / t _{TLH}	output transition time		7	15		19		22	ns	4.5	Fig.6
t _W	clock pulse width HIGH or LOW	16	9		20		24		ns	4.5	Fig.6
t _W	master reset pulse width LOW	16	8		20		24		ns	4.5	Fig.7
t _{rem}	removal time MR to CP	10	-2		13		15		ns	4.5	Fig.7
t _{su}	set-up time D _n to CP	12	5		15		18		ns	4.5	Fig.8
t _h	hold time D _n to CP	3	-4		3		3		ns	4.5	Fig.8
f _{max}	maximum clock pulse frequency	30	56		24		20		MHz	4.5	Fig.6

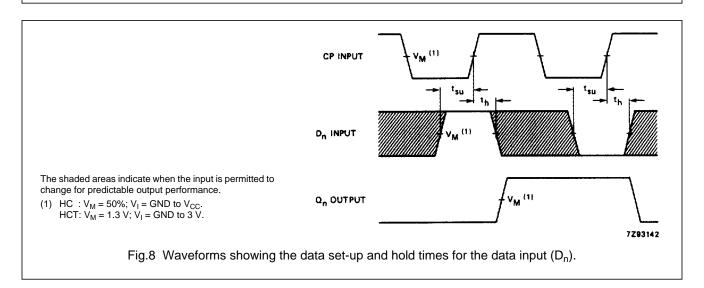
74HC/HCT273

AC WAVEFORMS









74HC/HCT273

PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".